

Field Emission Lighting Transparent Conductive Layer

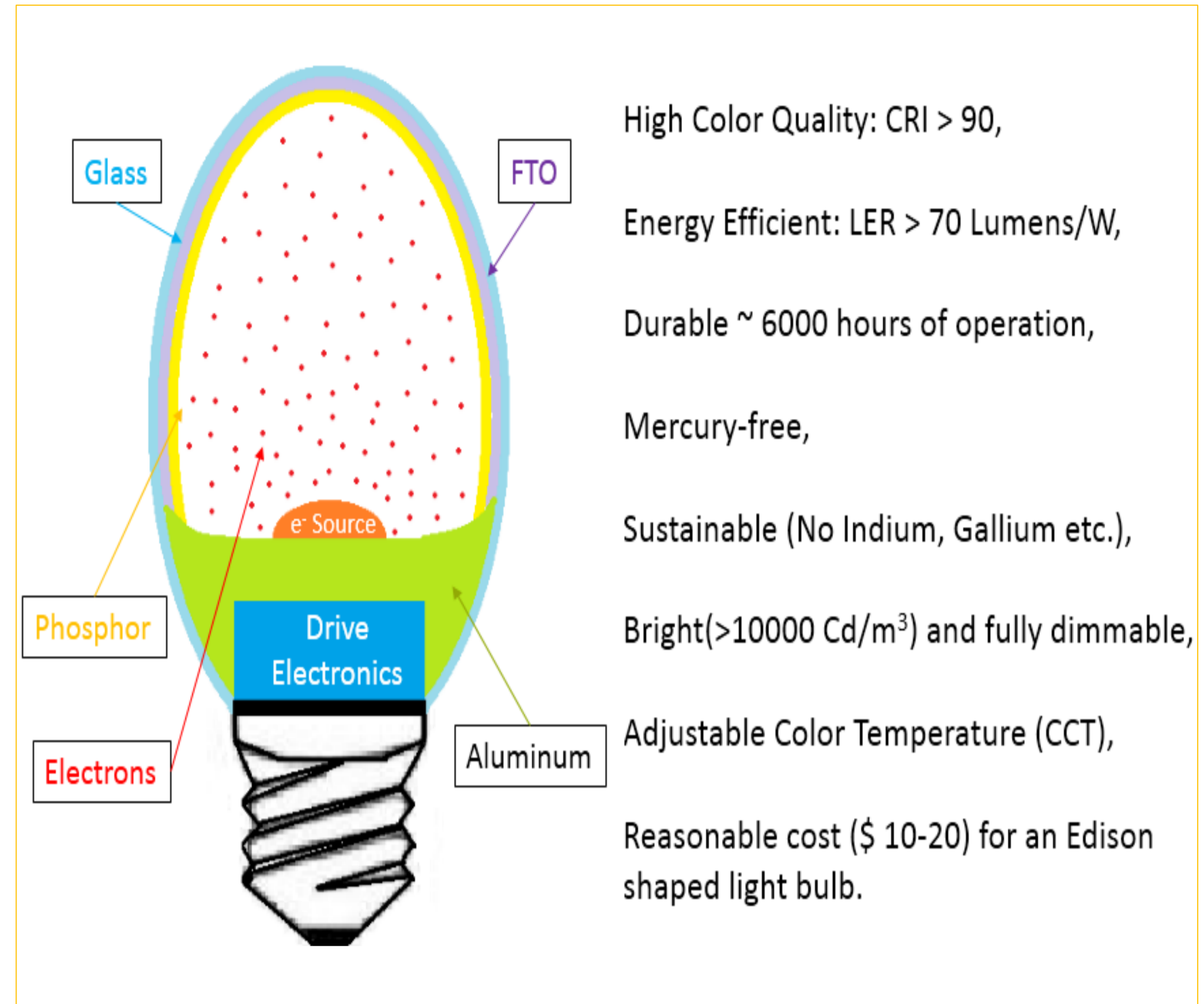


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Introduction

- Field Emission Lamps (FEL) are based on phosphors which are not good conductors (both electrically and thermally). This necessitates a conductive layer that is also transparent to visible spectrum.
- Most commonly used Transparent Conductive Oxide (TCO) is Tin doped Indium Oxide (ITO, $\text{Sn}:\text{In}_2\text{O}_3$).
- Indium's scarcity ($\approx 1\text{-}100$ ppm from ZnS ores) and increasing price ($\approx \$600\text{-}750/\text{kg}$) is a serious problem.
- Fluorine-doped Tin Oxide (FTO) is composed of sustainable elements and has similar transparency and considerable conductivity ($> 10^3$ S/cm).
- Tunability of Transmittance and Conductivity by varying Fluorine doping in Tin Oxide is possible to a large extent.
- Other candidates could be ZnO based TCOs such as Fluorine doped ZnO or Aluminum doped ZnO.



Motivation

- Use of FTO as a heat sink (anode) layer without compromising optical transparency is the main target.
- Use of low-cost fabrication techniques such as spray pyrolysis, and sol-gel coating.
- Better understanding of TCO layers by studying structural effects, film thickness and fabrication conditions with respect to FEL characteristics.

$$\frac{\kappa}{\sigma} = LT$$

κ, σ : thermal, electrical conductivity
T: temperature, L: a constant

Fabrication Routes

- Spray Pyrolysis: This technique uses a hot substrate to sinter active elements in precursor solution, usually gives best Figure of Merit in FTO coatings. Substrate temperature, precursor solution content, droplet sizes, atomizing gas pressure, solution flow rate are parameters of optimization.
- Sol-gel coating: the chemical process where a colloidal suspension of small particles are used to form a gel (network) of desired composition. Parameters include pH of the sol, type of solvent, source materials, deposition method and annealing temperature.

Comparison of Transparent Conductors

Property	Material
Highest transparency	ZnO:F, Cd ₂ SnO ₄
Highest conductivity	In ₂ O ₃ :Sn
Lowest plasma frequency	SnO ₂ :F, ZnO:F
Highest plasma frequency	Ag, TiN, In ₂ O ₃ :Sn
Highest work function, best contact to p-Si	SnO ₂ :F, ZnSnO ₃
Lowest work function, best contact to n-Si	ZnO:F
Best thermal stability	SnO ₂ :F, TiN, Cd ₂ SnO ₄
Best mechanical durability	TiN, SnO ₂ :F
Best chemical durability	SnO ₂ :F
Easiest to etch	ZnO:F, TiN
Best resistance to H plasmas	ZnO:F
Lowest deposition temperature	In ₂ O ₃ :Sn, ZnO:B, Ag
Least toxic	ZnO:F, SnO ₂ :F
Lowest cost	SnO ₂ :F

R. G. Gordon, "Criteria for Choosing Transparent Conductors," *MRS Bulletin*, (2000) vol. 25, pp. 52-57.

Figure of Merit for TCOs

$$\text{FOM} = \frac{T^q}{R_{\square}} = T^q * \sigma * d$$

T: transmittance

q: a number (10,20 or 100)

R_□: sheet resistance

σ: conductivity

d: film thickness

Our Goal: Increasing the electrical conductivity as much as possible without compromising from optical transmittance (T>85%).